## Phase diagram of the frustrated H ubbard m odel

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The M ott-H ubbard m etal-insulator transition in the param agnetic phase of the one-band H ubbard m odel has long been used to describe sim ilar features in real m aterials like  $V_2O_3$ . Here we show that this transition is hidden inside a rather robust antiferrom agnetic insulator even in the presence of com paratively strong m agnetic frustration. This result raises the question of the relevance of the M ott-H ubbard m etal-insulator transition for the generic phase diagram of the one-band H ubbard m odel.

The microscopic description of magnetism and metalinsulator transitions constitutes one of the major research activities in modern solid state theory. Especially transition metal compounds like V<sub>2</sub>O<sub>3</sub>, LaTiO<sub>3</sub>, NiS<sub>2 x</sub>Se<sub>x</sub> and the cuprates show metal-insulator transitions and magnetic order depending on composition, pressure or other control parameters [1]. The paramagnetic insulating phase observed in these materials is believed to be a so-called M ott-H ubbard insulator due to electronelectron correlations; in contrast to Slater or band insulators like SrT iO<sub>3</sub>.

The simplest model showing both magnetism and a correlation-induced metal-insulator transition (M II) is the one-band Hubbard model [2]

$$H = \sum_{i,j;}^{X} t_{ij}c_{i}^{y}c_{j} + \frac{U}{2} \sum_{i}^{X} n_{i}n_{i} :$$
 (1)

Considerable progress in understanding the physics of this simple but nevertheless non-trivial model has been achieved in the last decade through the developm ent of the dynamical mean-eld theory (DMFT) [3, 4, 5]. In particular, the phase diagram for the unfrustrated Hubbard model is very well understood [4, 5]. At half-lling the physics is dominated by an antiferrom agnetic insulating phase (AFI) for all U > 0 with a maximum W, where W is the bandwidth 0:15W around U Τ<sub>N</sub> of the non-interacting system . For nite doping, the antiferrom agnetic phase persists up to a critical doping c [6] and in addition shows phase separation [7, 8]. For very large values of U the antiferrom agnetic phase is replaced by a sm all region of N agaoka type ferrom agnetism [9, 10, 11].

Under rather special assumptions [12], it is possible to introduce complete magnetic frustration and suppress the antiferrom agnetic phase. In this case, a transition from a paramagnetic metal (PM) to a paramagnetic insulator (PI) becomes visible at half lling. At T = 0 it occurs at a value of the C oulom b parameter  $U_c$  1:5W [5, 6, 13]. Interestingly, the transition is of rst order [5, 14] for T > 0 with a second order end point at a  $T_c$  0:017W and  $U_c$  1:2W. Note that  $T_c$   $T_m^{max}$ .

A closer look at the phase diagram of  $V_2O_3$  [15] reveals a strikingly sim ilar scenario, and indeed the DM FT

results for the Hubbard model have been used as a qualitative explanation [5, 16]. For a proper description of this material, how ever, the antiferrom agnetic phase below T<sub>N</sub> 160K [15] has to be taken into account. It was argued and generally accepted [5] that the introduction of partial magnetic frustration will lead to the anticipated situation, where the M IT extends beyond the antiferromagnetic phase at low temperatures. The merging of these two transitions presents an interesting problem on its own, because it is commonly believed that the magnetic transition should be of second order. Furtherm ore, previous results for a system with magnetic frustration show, in addition to the desired e ect of reducing  $T_{\rm N}$ , an extended antiferrom agnetic m etallic (AFM ) phase at small U, preceeding the transition to the AFI [5, 17]. This observation suggests an appealing possibility to link the MIT in the param agnetic phase with a transition from an AFM to an AFI.

In this paper, we present results from a calculation using W ilson's num erical renorm alization group approach (NRG) [18] and exact diagonalization techniques (ED) [20] to solve the DM FT equations [5, 19] for the Hubbard model with m agnetic frustration at half lling. We show that frustration of the magnetic interactions through incorporation of suitable long-range hopping does not lead to the previously reported sequence PM \$ AFM \$ AFI with an extended region of an AFM at T = 0 [5, 17]. Instead, we observe a rst-order transition PM \$ AFI. Furtherm ore, the reduction of  $T_N$  is too small to result in the qualitative phase diagram of  $V_2O_3$ .

The natural choice for studying the elect of magnetic frustration is the simple hypercubic lattice with nearest and next-nearest neighbor hopping. In the DMFT, the lattice structure only enters via the dispersion of the non-interacting band states, and the corresponding k sums can conveniently be transformed into energy integrals using the free density of states (DOS) [5]. A further simplication arises if one considers lattices in the limit of large coordination number. Especially for the simple hypercubic lattice the DOS then becomes a Gaussian [3, 12] and the integrals can be performed analytically [4].

The investigation of magnetic properties is straightforward, too. In the case of the N  $\approx$  lattice is divided into A and B sublattices which results in a matrix structure of the DMFT equations [5]. An antiferrom agnetic N eel order then corresponds to a nite staggered m agnetization  $m_{\rm S} > 0$  with  $m_{\rm A} = m_{\rm S}$  and  $m_{\rm B} = m_{\rm S}$ . Unfortunately, the G aussian DOS of the hypercubic lattice has no realband edges, but stretches to in nity; the resulting exponential tails therefore prevent a clear distinction between m etal and insulator at T = 0, as has been observed in a Hartree calculation for the hypercubic lattice with next-nearest neighbor hopping [21].

G eorges et al. [5] suggested an extension of the DM FT equations for the B ethe lattice which introduces magnetic frustration with the DOS having nite support; this results in an analytically tractable form of the DM FT equations even for the AB-lattice.

For the standard Bethe lattice with nearest-neighbor hopping t and in the lim it of in nite coordination num ber the DM FT equations on an AB-lattice acquire the form [5]

$$G_{A} (z) = \frac{1}{z + A} (z) \frac{t^{2}}{4}G_{B} (z) ;$$

$$G_{B} (z) = \frac{1}{z + B} (z) \frac{t^{2}}{4}G_{A} (z) ;$$
(2)

Frustration is then introduced via additional terms in the denom inators of (2) [5, 17]

$$G_{A} (z) = \frac{1}{z + A(z) + \frac{t_{1}^{2}}{4}G_{B}(z) + \frac{t_{2}^{2}}{4}G_{A}(z)};$$

$$G_{B} (z) = \frac{1}{z + B(z) + \frac{t_{1}^{2}}{4}G_{A}(z) + \frac{t_{2}^{2}}{4}G_{B}(z)};$$
(3)

and the constraint  $t^2 = t_1^2 + t_2^2$ . In the param agnetic case, the equations (3) reduce to those of a standard B ethe lattice which, for example, result in the well-studied M otttransition. Furtherm ore, despite the frustration introduced, the system is still particle-hole symmetric. E specially for half lling this feature reduces the numerical e ort quite drastically. Note that a similar suggestion exists for the hypercubic lattice [12], too.

Invoking the symmetry  $G_A(z) = G_B(z)$  valid for the Neel state, eqs. (3) reduce to two coupled nonlinear equations which we solve iteratively. In the course of the iterations, the quantity (z) has to be calculated from the solution of a generalized single in purity Anderson m odel [5]. For that task we employ the NRG [18], suitably extended to treat spin-polarized situations [8, 22].

Let us not discuss the results for the magnetization as function of U for T = 0. In the following, we x  $t_2=t_1 = 1 = 3$  0.58 [23] and use the bandwidth W of the non-interacting system as our energy scale. The NRG results in Fig. 1 (circles) show a completely different behavior as compared to the ED data (diamonds) from ref. 17. Instead of a continuous increase of the stag-

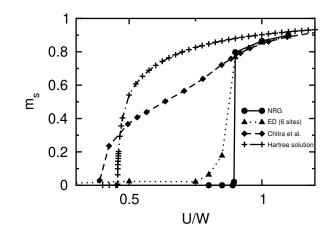


FIG.1: Staggered m agnetization m  $_{\rm S}$  as function of U at T = 0. The circles are the results from NRG; the triangles from an ED calculation for 6 sites, while the diam onds are taken from ref. 17. For comparison, the results of a Hartree calculation are given by the crosses.

gered magnetization  $m_{\rm S}$  for U > U<sub>c</sub> 0:4W as suggested by both a Hartree calculation (crosses) and the data from ref. 17, we nd a jump in  $m_s$  at a considerably larger U<sub>c</sub> 0:9W . To clarify this discrepancy, we perform ed ED calculations, resulting in the triangles shown in Fig.1.We nd good agreem entwith our NRG results, the transition system atically approaching the NRG curve with increasing size of the system diagonalized in the ED procedure. W e furtherm ore observed a rather strong dependence of the ED results on details of the num erical procedure, especially on the energy cuto introduced in calculating G (z). Decreasing this cuto system atically shifts the ED result towards the one found in [17]. The NRG, on the other hand, is stable with respect to changes in the param eters controlling its num erical accuracy.

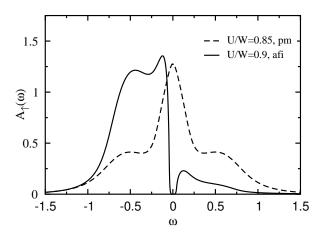


FIG. 2: Density of states for spin up on an A lattice site as function of frequency.

A nother in portant question is the existence of an anti-

ferrom agnetic m etallic solution of the DMFT equations. Figure 2 shows the NRG results for the DOS for T = 0and spin up on an A lattice site. Due to particle-hole symmetry the DOS for spin down on A sites (or spin up on B sites) can be obtained by ! ! . The full and dashed lines represent the AFI solution for U & U<sub>c</sub> and the PM solution for U % U<sub>c</sub>, respectively. C learly, the m agnetic solution is insulating with a well-developed gap at the Ferm i energy. Quite generally, we were not able to nd a stable AFM solution at T = 0.

The discontinuity in the staggered magnetization m $_{\rm S}$  at the transition PM \$ AFI im plies a rst order transition and the existence of a hysteresis region. Indeed, starting

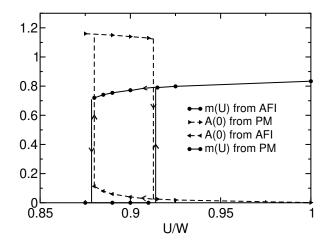


FIG.3: Staggered m agnetization (solid lines) and total DOS at the Ferm i energy (dashed lines) as function of U in the vicinity of  $U_{\rm c}$  for T=0.0155W. The arrows indicate that the DMFT solutions have been obtained by either increasing U (!) or decreasing U ().

from the param agnet at U  $U_c$  and increasing U results in a m agnetization curve di erent from the one obtained by starting at U  $U_c$  and decreasing U. This is apparent from Fig.3 (fulllines) where a region of hysteresis can be observed in the staggered m agnetization (for tem perature T = 0:0155W). At the same time the total DOS at the Ferm i energy A (0) = A  $_{*}$  (0) + A  $_{\#}$  (0) show s hysteresis between m etallic and insulating behavior in exactly the same U region. Note, that due to the nite tem perature the DOS at the Ferm i level is not exactly zero in the N eel state, but strongly reduced as com pared to the m etal [14].

It is of course in portant to verify that the hysteresis found for sm all U is not som e kind of artefact. This can m ost conveniently be shown by looking at the transition at large U. Due to the mapping of the Hubbard m odel to a H eisenberg m odel in this regime, one should expect the transition to be of second order, with the staggered m agnetization vanishing continously likem  $_{\rm S}$  /  ${\rm T_N}$  T when approaching  $T_{\rm N}$  from below. That this is indeed the case is apparent from Fig. 4, where we show the

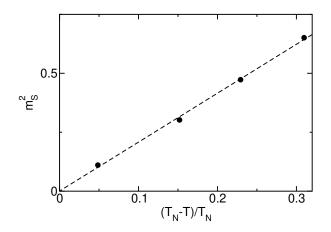


FIG .4: Squared staggered m agnetization m  $_S$  as function of T at U=W = 2. Note that m  $_S^2$  vanishes continously like  $T_N$   $\,$  T as T &  $T_N$  .

squared staggered magnetization as function of T for U=W=2. The transition is thus of second order with the expected mean-eld exponent in this region of the phase diagram.

Collecting the results for the transitions and the hysteresis region for di erent temperatures leads to the phase diagram in Fig. 5. An enlarged view of the re-

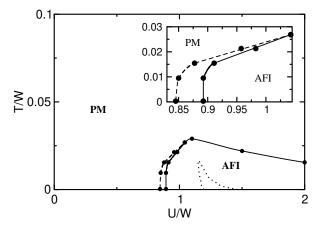


FIG.5: M agnetic phase diagram for the H ubbard model with frustration as de ned by eqs. (3) and  $t_2=t_1 = 1 = \overline{3}$ . The dotted lines inside the AFI denote the coexistence region for the param agnetic M IT. The inset shows an enlarged view of the region with coexistence of PM and AFI.

gion showing coexistence of PM and AFI is given in the inset, where the full line represents the transition PM ! AFI with increasing U and the dashed line the transition AFI! PM with decreasing U. These two lines seem to merge at a value of U W for this particular value of  $t_2$ , with a critical tem perature for this endpoint  $T_c$  0.02W. Note that, even in the presence of such a sizeable  $t_2$ , the antiferrom agnetic phase still com pletely

encom passes the param agnetic M II (dotted lines in the main panel of Fig. 5 [14]).

It is, of course, interesting to see how the magnetic phase evolves with increasing  $t_2$  and in particular how its boundary crosses the paramagnetic M IT .W e nd that increasing  $t_2$  does not change the form of the magnetic phase in Fig. 5 qualitatively, but mainly shifts the lower

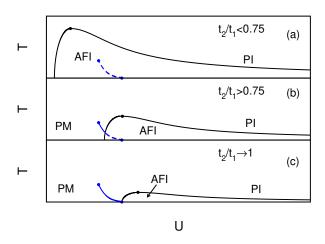


FIG. 6: Schem atic evolution of the magnetic phase diagram with increasing frustration. The dots on the phase transition lines denote the critical endpoints of the rst order transitions.

critical U and decreases the maximum  $T_{\rm N}$ . The calculated estimates for those two quantities as function of  $t_2$  lead to the schematic evolution of the phase diagram presented in Fig. 6a-c. Here, only the true phase boundaries are shown. A direct calculation of the free energy at -nite temperatures is presently not possible with the NRG method, so we cannot calculate the actual transition line separating the paramagnetic and AF phases. The transition lines in Fig. 6a-c are therefore a guide to the eye only. For the M ott transition, the position of the actual transition line has been calculated in ref. 24.

Figure 6a shows the qualitative phase diagram corresponding to Fig. 5 with the line of rst order transitions ending in a critical point. Upon further increasing the value of to, the rst order transition lines from both the PM \$ AFI and the M ott transition cross (Fig. 6b), thus exposing a nite region of the M ott insulator and a transition PI\$ AFI. Finally, for even higher values of t2, the PM \$ AFI transition at T = 0 approaches the M ott transition and  $T_N$  is reduced signi cantly (Fig. 6c). Note that in the limiting case  $t_2 = t_1$  the AFI phase completely vanishes due to the structure of the DMFT equations (3). However, for t<sub>2</sub> ! t<sub>1</sub> there is always a nite antiferrom agnetic exchange J /  $(t_1^2)$ t)=U which is su cient to stabilize an antiferrom agnetic ground state for U > U<sub>c</sub> of the M ott transition.

From these results we conclude that frustration as introduced via eqs. (3) is not su cient to qualitatively reproduce the phase diagram of materials like  $V_2O_3$ . In particular, the M ott transition extends beyond the AFI region only for unphysically large values of  $t_2$ .

The question remains whether it is possible at all to reproduce qualitatively the scenario observed in  $V_2O_3$  within a one-band m odel. Based on our results reported here, we rather believe that one has to take into account additional degrees of freedom, for example phonons (within a Holstein-Hubbard m odel) or orbital degeneracies (within a multi-band Hubbard m odel).

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